

<b>Notice of References Cited</b>	Application/Control No. 10/780,671	Applicant(s)/Patent Under Reexamination YADAV, TAPESH	
	Examiner Kallambella Vijayakumar	Art Unit 1751	Page 1 of 1

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**NON-PATENT DOCUMENTS**

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	W	Valle et "Transparent and Conductive ZnO:Al thin films prepared by sol-gel dip-coating," J. Eu. Cer. Soc., 2004, 24, 1009-1013.
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\*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)  
Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.